## NSN 5961-01-529-9657

**Fiig:** A110a0



Diode Semiconductor Device - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-529-9657 **Overall Length:** Between 2.85 millimeters and 3.10 millimeters **Terminal Length:** Between 0.2 millimeters and 0.6 millimeters **Overall Height:** Between 1.0 millimeters and 1.4 millimeters Overall Width: Between 2.5 millimeters and 3.0 millimeters **Function For Which Designed:** Zener diode **End Application:** 4935-01-136-0233, shop equipment, guided missile system; missile, patriot Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-236 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 2.4 regulator voltage **Current Rating Per Characteristic:** 5.00 milliamperes all primaries horsepower metric **Power Rating Per Characteristic:** 200.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Pin 1 anode; pin 2 not connected; pin 3 cathode **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No